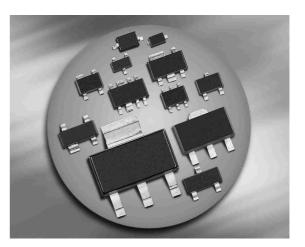




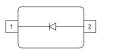
Silicon Tuning Diode

- Excellent linearity
- High Q hyperabrupt tuning diode
- Low series resistance
- High capacitance ratio
- Designed for low tuning voltage operation for VCO's in mobile communications equipment
- For control elements such as TCXOs and VCXOs

BBY57-05W



BBY57-02L	
BBY57-02V	
BBY57-02W	





Туре	Package	Configuration	L_S (nH)	Marking
BBY57-02L*	TSLP-2	single	0.4	55
BBY57-02V	SC79	single	0.6	5
BBY57-02W	SCD80	single	0.6	55
BBY57-05W	SOT323	common cathode	1.4	D5s

* Preliminary

Maximum Ratings at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V _R	10	V
Forward current	I _F	20	mA
Operating temperature range	T _{op}	-55 125	°C
Storage temperature	T _{stg}	-55 150	



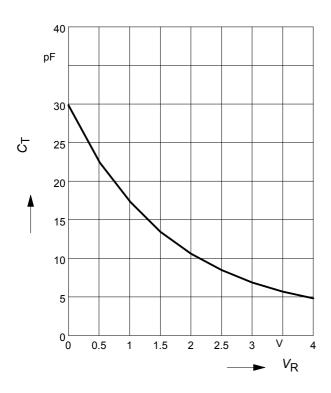
Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Reverse current	I _R				nA
<i>V</i> _R = 8 V		-	-	10	
<i>V</i> _R = 8 V, <i>T</i> _A = 85 °C		-	-	100	
AC Characteristics		-		-	
Diode capacitance	CT				pF
V _R = 1 V, <i>f</i> = 1 MHz		16.5	17.5	18.6	
V _R = 2.5 V, <i>f</i> = 1 MHz		-	9.35	-	
V _R = 3 V, <i>f</i> = 1 MHz		-	7	-	
$V_{R} = 4 V, f = 1 MHz$		3.5	4.7	5.5	
Capacitance ratio	C _{T1} /C _{T3}	-	2.45	-	
V _R = 1 V, V _R = 3 V, <i>f</i> = 1 MHz					
Capacitance ratio	C _{T1} /C _{T4}	3	3.7	4.5	1
V _R = 1 V, V _R = 4 V, <i>f</i> = 1 MHz					
Series resistance	r _S				Ω
V _R = 1 V, <i>f</i> = 470 MHz, BBY57-02L		-	0.35	-	
V_{R} = 1 V, f = 470 MHz, all others		-	0.3	-	

Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified

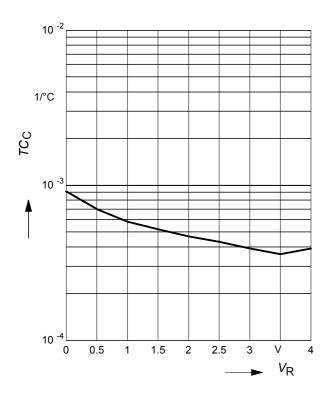


Diode capacitance $C_{T} = f(V_{R})$

f = 1MHz

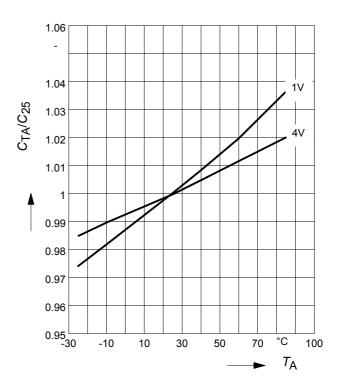


Temperature coefficient of the diode capacitance $T_{CC} = f(V_R)$



Normalized diode capacitance

 $C_{(TA)}/C_{(25^{\circ}C)} = f(T_A); f = 1MHz$



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